

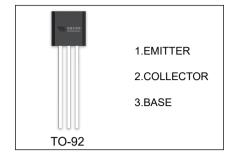
2SC5344 TRANSISTOR (NPN)

FEATURES

• Audio Power Amplifier Application

• High h_{FE}: h_{FE}=100~320

• Complementary to 2SA1981



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SC5344	TO-92	Bulk	1000pcs/Bag
2SC5344-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	35	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current -Continuous	800	mA
Pc	Collector Power Dissipation	625	mW
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	℃



T_a =25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA, I _B =0	35			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 10mA, I _B =0	30			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 0.01mA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =35V , I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 5V, I _C =0			0.1	μA
DC current gain	h _{FE}	V _{CE} =1V, I _C = 100mA	100		320	
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	I _C = 500mA, I _B =50mA			0.5	V
Transition frequency	f _T	V _{CE} =5V, I _C =10mA		120		MHz
Collector Output Capacitance	C_ob	V _{CB} =10V,I _E = 0,f=1MHz		13		pF

CLASSIFICATION OF h_{FE}

Rank	0	Y
Range	100-200	160-320



